¹⁶⁷Ta ε decay (80 s) 1982Li17,1987Es08

History							
Туре	Author	Citation	Literature Cutoff Date				
Full Evaluation	Balraj Singh and Jun Chen	NDS 191,1 (2023)	22-Aug-2023				

Parent: ¹⁶⁷Ta: E=0.0; $J^{\pi}=(3/2^+)$; $T_{1/2}=80$ s 4; $Q(\varepsilon)=5120$ 40; $\%\varepsilon+\%\beta^+$ decay=100

 167 Ta-J^{π},T_{1/2}: From 167 Ta Adopted Levels.

¹⁶⁷Ta-Q(ε): From 2021Wa16.

1982Li17: ¹⁶⁷Ta from Lu(³He,xn), $E(^{3}He)=280$ MeV using Lu metal and Lutetium fluoride targets, followed by fluorination of products and mass separation. Measured E γ , I γ using Si(Li) and coaxial Ge(Li) detectors.

1987Es08, 1989Br19: ¹⁶⁷Ta from ¹⁵¹Eu(²²Ne,6n), followed by chemical separation and aerosol transport. Measured E γ , half-life of ¹⁶⁷Ta and ¹⁶⁷Hf decays from decay curves for γ rays.

Others:

1992HeZV: measured $E\gamma$, $I\gamma$, half-life.

1969Ar22: ¹⁶⁷Ta produced in Re,Hg(p,X) reaction, measured half-life of the decay of ¹⁶⁷Ta.

Additional information 1.

The decay scheme is unknown, except for possible population of the first excited state at 92.3 keV.

¹⁶⁷Hf Levels

E(level)	$J^{\pi \dagger}$	T _{1/2} †
0.0	$(5/2^{-})$	2.05 min 5
92.3?	$(7/2^{-})$	

[†] From the Adopted Levels.

 $\gamma(^{167}\text{Hf})$

E_{γ}^{\dagger}	E _i (level)	\mathbf{J}_i^{π}	$\mathbf{E}_f \mathbf{J}_f^{\pi}$	Comments
^x 81.6				
92.3 [‡]	92.3?	(7/2 ⁻)	0.0 (5/2 ⁻)	E_{γ} : consistent with that for known transition deexciting first excited state of ¹⁶⁷ Hf; tentatively placed by evaluators.
^{<i>x</i>} 111.6				
^x 113.7				γ also reported in 1987Es08.
^x 118.6				
^x 139.5 4				E_{γ} : from 1987Es08. E_{γ} =139.5 in 1982Li17.
^x 214.2				
^x 278.0				Other E γ : 277.7 in 1987Es08, 280.0 (1992HeZV).
^x 296.3				

[†] From 1982Li17, except as noted. No uncertainties are given by the authors.

 \ddagger Placement of transition in the level scheme is uncertain.

 $x \gamma$ ray not placed in level scheme.

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Decay Scheme

